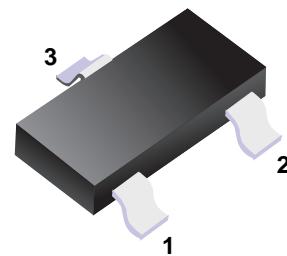


■ Switching Diodes

■ Features

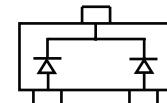
- Small plastic SMD package.
- High switching sped: max.4 ns.
- Repetitive peak forward current: max.450 mA.



■ Simplified outline(SOT-23)

■ Marking

Marking	A4
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■ Absolute Maximum Ratings Ta = 25°C

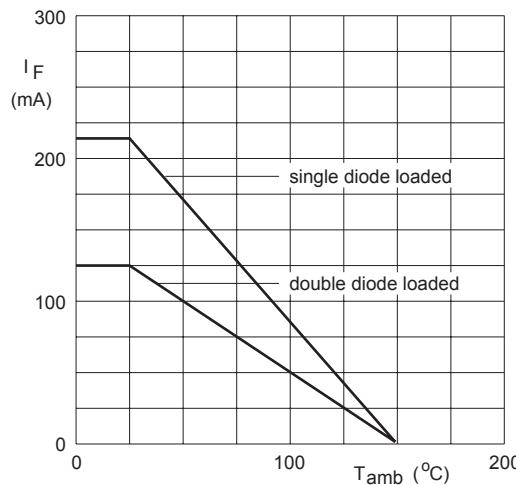
Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	V _R RM	85	V
Continuous reverse voltage	V _R	75	V
Continuous forward current(single diode loaded *) (double diode loaded *)	I _F	215 125	mA
Repetitive peak forward current	I _{FRM}	450	mA
Non-repetitive peak forward current T _j =25 °C t=1 μ s t=1ms t=1s	I _{FSM}	4 1 0.5	A
power dissipation *	P _D	250	mW
Thermal resistance from junction to tie-point	R _{th j-tp}	360	K/W
Thermal resistance from junction to ambient *	R _{th j-a}	500	K/W
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

* Device mounted on an FR4 printed-circuit board.

■ Electrical Characteristics Ta = 25°C

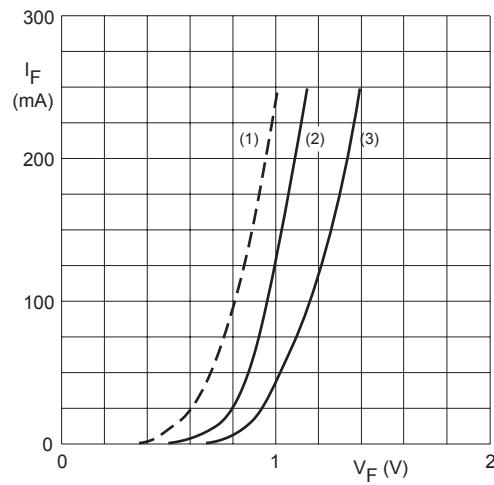
Parameter	Symbol	Test conditions	Max	Unit
Forward voltage	V _F	I _F =1 mA	715	mV
		I _F =10 mA	855	mV
		I _F =50 mA	1	V
		I _F =150 mA	1.25	V
Reverse current	I _R	V _R =75 V	1	
		V _R =25 V; T _j = 150 °C	30	μA
		V _R =75 V; T _j = 150 °C	50	
Diode capacitance	C _d	V _R =0 V, f= 1 MHz	1.5	pF
Reverse recovery time	t _{rr}	when switched from I _F = 10 mA to I _R =10mA;R _L =100 Ω ; measured at I _R = 1mA	4	nS
Forward recovery voltage	V _{fr}	I _F = 10 mA, t _r = 20 ns	1.75	V

■ Typical Characteristics



Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.

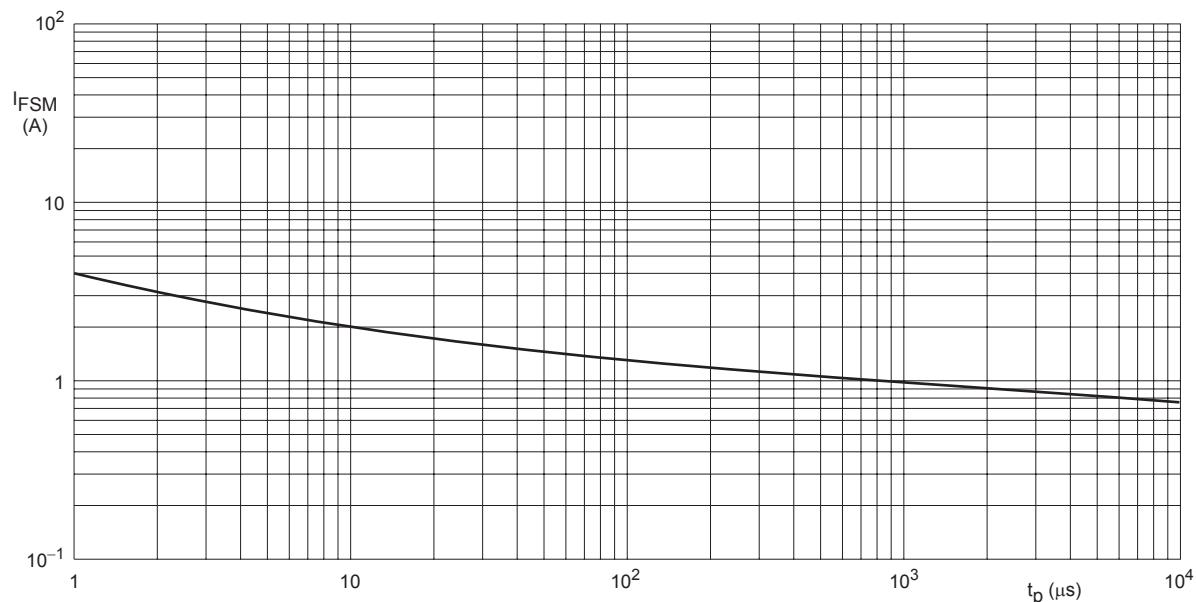


(1) $T_j = 150 \text{ }^\circ\text{C}$; typical values.

(2) $T_j = 25 \text{ }^\circ\text{C}$; typical values.

(3) $T_j = 25 \text{ }^\circ\text{C}$; maximum values.

Fig.3 Forward current as a function of forward voltage.



Based on square wave currents.
 $T_j = 25 \text{ }^\circ\text{C}$ prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

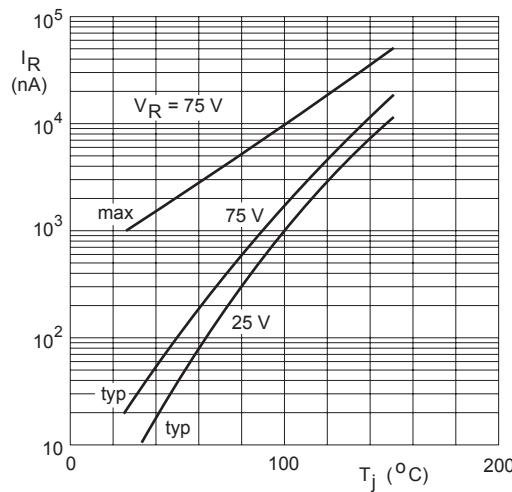


Fig.5 Reverse current as a function of junction temperature.

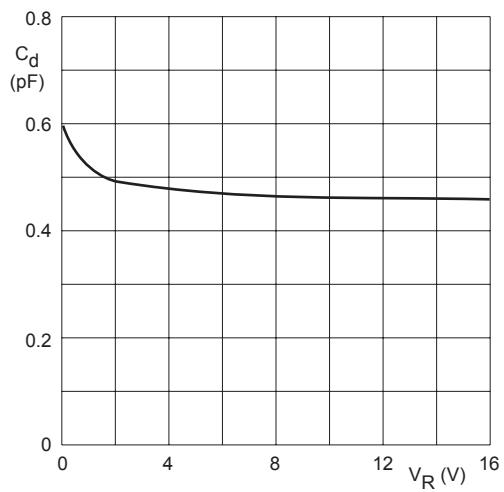
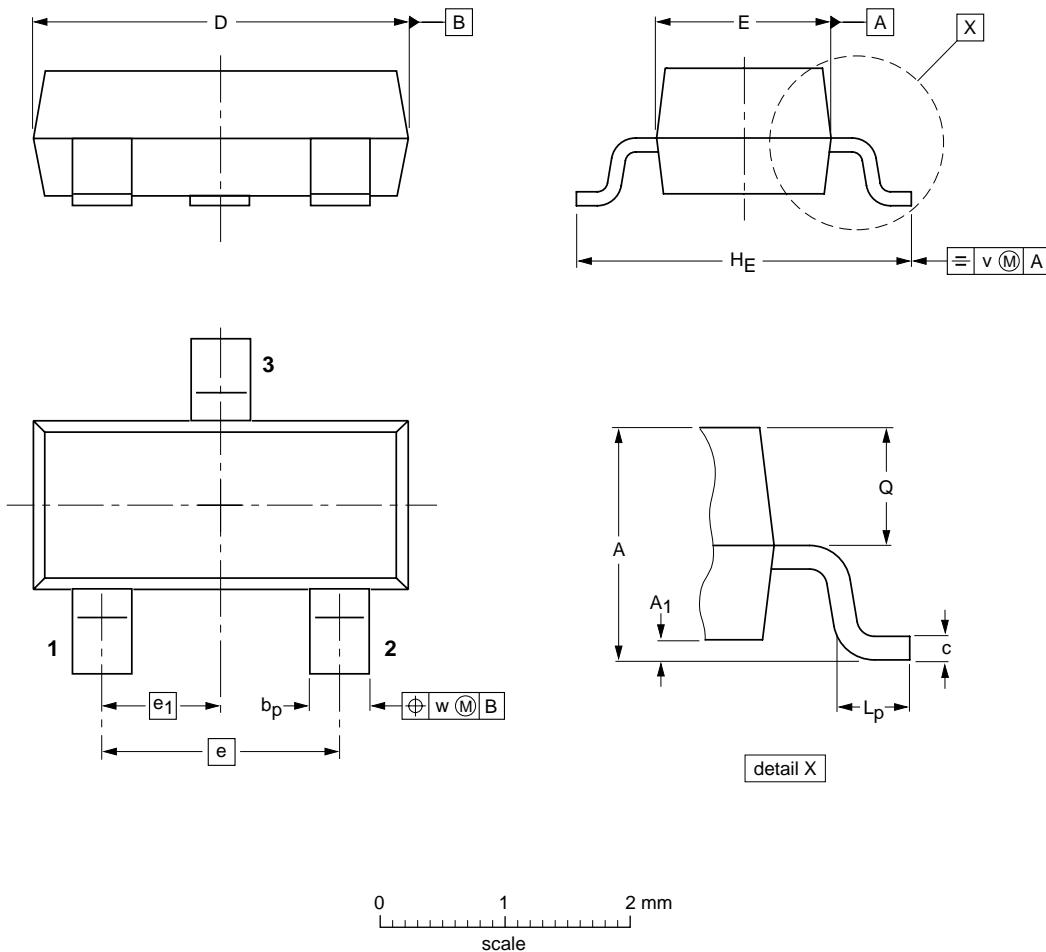


Fig.6 Diode capacitance as a function of reverse voltage; typical values.

Package Outline

SOT-23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard
SOT-23	Tape/Reel,7"reel	3000	EIA-481-1

单击下面可查看定价，库存，交付和生命周期等信息

[>>YFW\(佑风微\)](#)